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RoHS

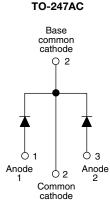
COMPLIANT

HALOGEN

FREE

HEXFRED[®] Ultrafast Soft Recovery Diode, 2 x 25 A





PRODUCT SUMMARY								
Package	TO-247AC							
I _{F(AV)}	2 x 25 A							
V _R	600 V							
V _F at I _F	1.3 V							
t _{rr} typ.	23 ns							
T _J max.	150 °C							
Diode variation	Common cathode							

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{BBM} and Q_{rr}
- Designed and gualified according to JEDEC[®]-JESD47
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

VS-HFA50PA60C... is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 25 A per leg continuous current, the VS-HFA50PA60C... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA50PA60C... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Cathode to anode voltage	V _R		600	V					
Maximum continuous forward currentper leg	I_	T _C = 100 °C	25						
per device	IF	$1_{\rm C} = 100$ C	50	А					
Single pulse forward current	I _{FSM}		225	~					
Maximum repetitive forward current	I _{FRM}		100						
Movimum power discipation	р	T _C = 25 °C	150	W					
Maximum power dissipation	P _D	T _C = 100 °C	60	٧V					
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C					

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Document Number: 94074

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ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25 \text{ °C}$ unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS		
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	600	-	-				
Maximum forward voltage		I _F = 25 A		-	1.3	1.7	V		
	V _{FM}	I _F = 50 A	See fig. 1	-	1.5	2.0			
		I _F = 25 A, T _J = 125 °C]	-	1.3	1.7			
Maximum reverse	1	$V_{R} = V_{R}$ rated	See fig. 2	-	1.5	20			
leakage current	I _{RM}	T_J = 125 °C, V_R = 0.8 x V_R rated	See lig. 2	-	600	2000	μA		
Junction capacitance	CT	V _R = 200 V See fig. 3		-	55	100	pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body - 12 -				-	nH		

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$	A/μs, V _R = 30 V	-	23	-			
Reverse recovery time See fig. 5, 10	t _{rr1}	T _J = 25 °C		-	50	75	ns		
000 lig. 0, 10	t _{rr2}	T _J = 125 °C		-	105	160			
Peak recovery current	I _{RRM1}	T _J = 25 °C	I _F = 25 A dI _F /dt = 200 A/μs	-	4.5	10	A		
See fig. 6	I _{RRM2}	T _J = 125 °C		-	8.0	15			
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	112	375			
See fig. 7	Q _{rr2}	T _J = 125 °C	V _R = 200 V	-	420	1200	nC		
Peak rate of fall of recovery current during t _b See fig. 8	dl _{(rec)M} /dt1	T _J = 25 °C		-	250	-	A∕µs		
	dl _{(rec)M} /dt2	T _J = 125 °C		-	160	-	Ανμs		

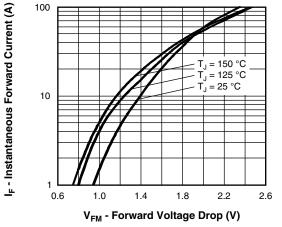
THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C				
Junction to case, single leg conducting	P		-	-	0.83					
Junction to case, both legs conducting			-	-	0.42	κ/w				
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	- r./ v v				
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.25	-	-				
Weight			-	6.0	-	g				
weight			-	0.21	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style TO-247AC	HFA50PA60C							

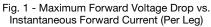
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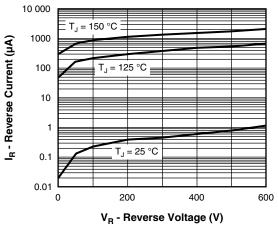
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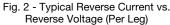


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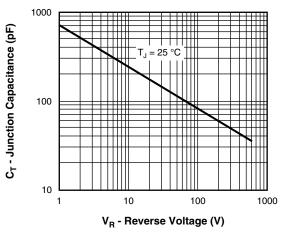


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

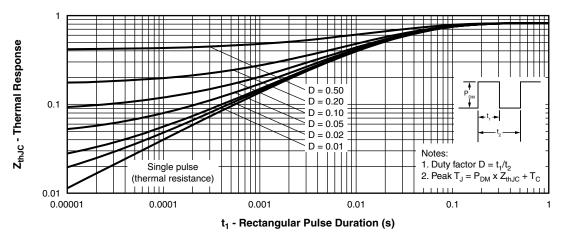


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

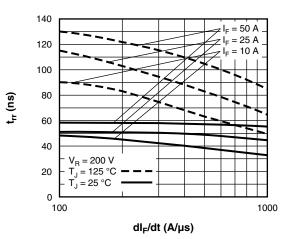
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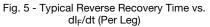
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VS-HFA50PA60CPbF, VS-HFA50PA60C-N3

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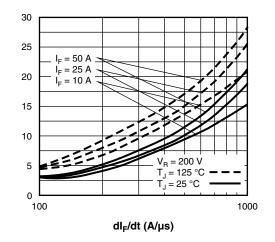


Fig. 6 - Typical Recovery Current vs. dl_F/dt (Per Leg)

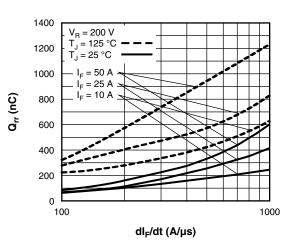
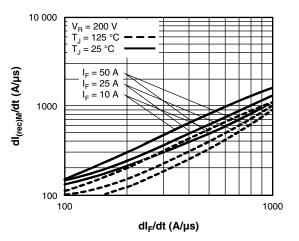


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)





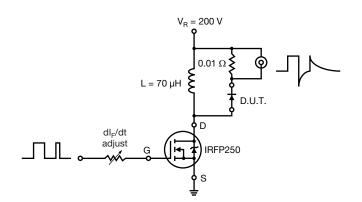


Fig. 9 - Reverse Recovery Parameter Test Circuit

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I_{rr} (A)

ISHAY



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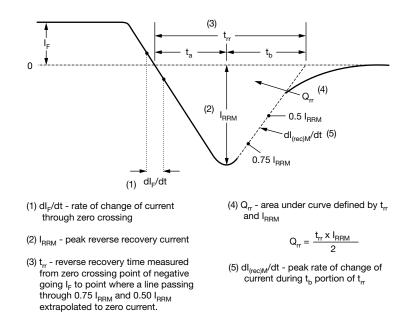
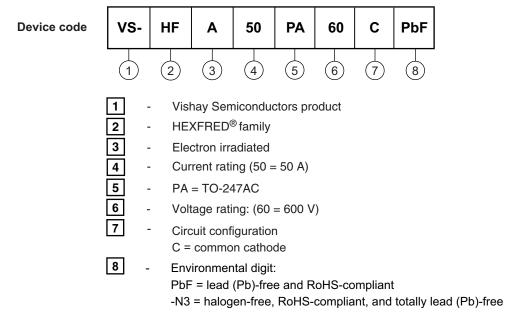


Fig. 10 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-HFA50PA60CPbF	25	500	Antistatic plastic tube						
VS-HFA50PA60C-N3	25	500	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95542					
Part marking information	TO-247ACPbF	www.vishay.com/doc?95226					
	TO-247AC-N3	www.vishay.com/doc?95007					

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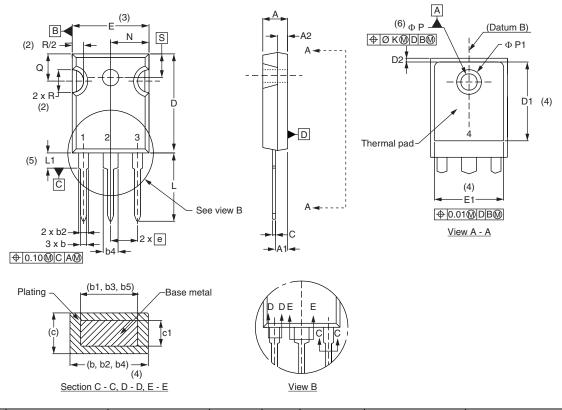
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TO-247 - 50 mils L/F

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			Е	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			N	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	7.39	-	0.291	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

 $^{(7)}$ Outline conforms to JEDEC $^{\tiny (\! R \!)}$ outline TO-247 with exception of dimension c and Q

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